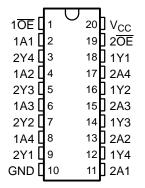




FEATURES

- Operates From 2.7 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 6.5 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC} = 3.3 V, T_A = 25°C
- I_{off} and Power-Up 3-State Support Hot Insertion
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

This octal buffer/driver is designed for 2.7-V to 3.6-V V_{CC} operation.

The SN74LVCZ240A is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

This device is organized as two 4-bit buffers/drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

ORDERING INFORMATION

T _A	PAG	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 20	SN74LVCZ240AN	SN74LVCZ240AN
	COIC DW	Tube of 25 SN74LVCZ240ADW		11/070404
	SOIC – DW	Reel of 2000	SN74LVCZ240ADWR	LVCZ240A
	SOP - NS	Reel of 2000	SN74LVCZ240ANSR	LVCZ240A
-40°C to 85°C	SSOP - DB	Reel of 2000	SN74LVCZ240ADBR	CV240A
		Tube of 70	SN74LVCZ240APW	
	TSSOP - PW	Reel of 2000	SN74LVCZ240APWR	CV240A
		Reel of 250	SN74LVCZ240APWT	
	TVSOP - DGV	Reel of 2000	SN74LVCZ240ADGVR	CV240A

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

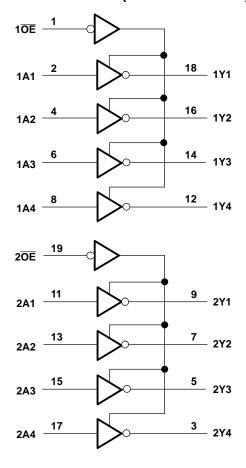
When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

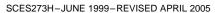
This device is fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

FUNCTION TABLE (EACH BUFFER)

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	L
L	L	Н
Н	X	Z

LOGIC DIAGRAM (POSITIVE LOGIC)







Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	6.5	V
V_{I}	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the	high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
Vo	Voltage range applied to any output in the	high or low state (2)(3)	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	ontinuous output current			mA
	Continuous current through V _{CC} or GND			±100	mA
		DB package		70	
		DGV package		92	
0	Deckage thermal impedance (4)	DW package		58	°C/W
θ_{JA}	Package thermal impedance (4)	N package		69	C/VV
		NS package		60	
		PW package		83	
T _{stg}	Storage temperature range		-65	150°C	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.7	3.6	V
V _{IH}	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 2.7 V to 3.6 V		8.0	V
V _I	Input voltage		0	5.5	V
V	Output voltage	High or low state	0	V_{CC}	V
Vo	Output voltage	3-state	0	5.5	V
	High level output ourrent	V _{CC} = 2.7 V		-12	m Λ
I _{OH}	High-level output current	V _{CC} = 3 V		-24	mA
	Lour lovel output ourrent	V _{CC} = 2.7 V		12	m Λ
I _{OL}	Low-level output current	V _{CC} = 3 V		24	mA
Δt/Δν	Input transition rise or fall rate			6	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		150		μs/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the recommended operating conditions table.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDI	TIONS	V _{cc}	MIN	TYP ⁽¹⁾ MAX	UNIT
	$I_{OH} = -100 \mu A$		2.7 V to 3.6 V	V _{CC} - 0.2		
V	12 1		2.7 V	2.2		V
V_{OH}	$I_{OH} = -12 \text{ mA}$		3 V	2.4		V
	$I_{OH} = -24 \text{ mA}$		3 V	2.2		
	$I_{OL} = 100 \mu A$	O _L = 100 μA			0.2	
V_{OL}	I _{OL} = 12 mA		2.7 V		0.4	V
	I _{OL} = 24 mA		3 V		0.55	
I _I	V _I = 0 to 5.5 V		3.6 V		±5	μΑ
l _{off}	V_I or $V_O = 5.5 \text{ V}$		0		±5	μΑ
I _{OZ}	V _O = 0 to 5.5 V		3.6 V		±5	μΑ
I _{OZPU}	$V_O = 0.5 \text{ to } 2.5 \text{ V},$	= don't care	0 to 1.5 V		±5	μΑ
I _{OZPD}	$V_O = 0.5 \text{ to } 2.5 \text{ V},$	= don't care	1.5 V to 0		±5	μΑ
	$V_I = V_{CC}$ or GND	- 0	3.6 V		100	^
I _{CC}	$I_0 = \frac{1}{3.6 \text{ V} \le \text{V}_1 \le 5.5 \text{ V}^{(2)}}$	= 0	3.0 V		100	μΑ
Δl _{CC}	One input at V _{CC} - 0.6 V, Other i	nputs at V _{CC} or GND	2.7 V to 3.6 V		100	μΑ
C _i	$V_I = V_{CC}$ or GND		3.3 V		3.5	pF
C _o	$V_O = V_{CC}$ or GND		3.3 V		5.5	pF

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C. (2) This applies in the disabled state only.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2	2.7 V	V _{CC} = 3 ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(001F01)	MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A		7.5	1.3	6.5	ns
t _{en}	ŌĒ	A or B		9	1.1	8	ns
t _{dis}	ŌĒ	A or B		8	1.4	7	ns

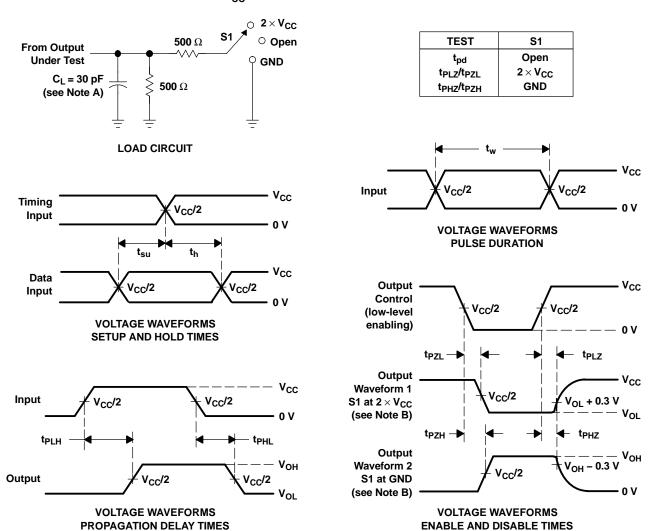
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V _{CC} = 3.3 V TYP	UNIT
_	Dower dissipation conscitance per huffer/driver	Outputs enabled	f = 10 MHz	37	pF
C _{pd}	Power dissipation capacitance per buffer/driver	Outputs disabled	I = IO MINZ	3	ρг



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.7 \text{ V}$ and $3.3 \text{ V} \pm 0.3 \text{ V}$



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , $t_r \leq$ 2 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





23-Aug-2017

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVCZ240ADW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ240A	Samples
SN74LVCZ240ANSR	ACTIVE	so	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ240A	Samples
SN74LVCZ240APW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV240A	Samples
SN74LVCZ240APWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV240A	Samples
SN74LVCZ240APWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV240A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: Til defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

23-Aug-2017

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PACKAGE MATERIALS INFORMATION

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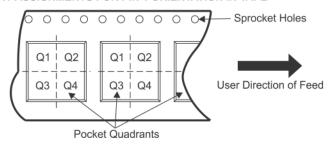
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCZ240ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1

www.ti.com 20-Dec-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCZ240ANSR	SO	NS	20	2000	367.0	367.0	45.0

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE

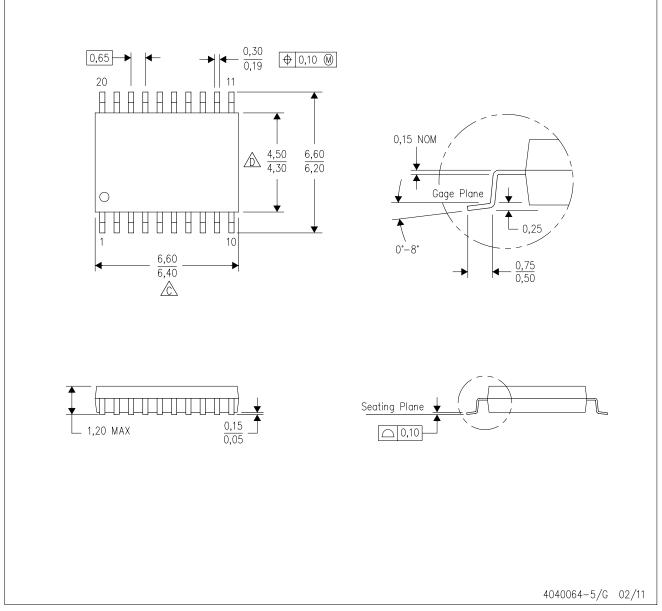


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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